

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Transmissive Sensor

FEATURES

- Phototransistor output
- · Accurate position sensing
- · Four mounting configurations
- 0.125 in.(3.18 mm) slot width
- Choice of detector aperture
- · Choice of opaque or IR transmissive housings



DESCRIPTION

The HOA086X/087X series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black thermoplastic housing. The phototransistor switching takes place whenever an opaque object passes through the slot between emitter and detector. This series allows the user to choose from available options: (1) mounting tab configurations, (2) lead spacing, (3) electro-optical characteristics, (4) detector aperture size, and (5) housing materials.

The HOA086X series utilizes an IR transmissive polysulfone housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA087X series employs an opaque polysulfone housing with aperture openings for use in applications in which maximum rejection of ambient light is important and in situations where maximum position resolution is desired. The HOA086X/087X series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

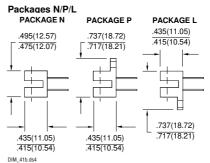
To specify the complete product characteristics, see the PART NUMBER GUIDE.

OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)

Package T - DIA 2 PLCS

DIM 041a cdr



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Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

Transmissive Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| ELECTRICAL CHARACTERISTICS (25 © unites source wise index) | | | | | | |
|--|---------------------------------|-----|-----|-----|-------|---|
| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| IR EMITTER | | | | | | |
| Forward Voltage | VF | | | 1.6 | V | I _F =20 mA |
| Reverse Leakage Current | l _R | | | 10 | μΑ | V _R =3 V |
| DETECTOR | | | | | | |
| Collector-Emitter Breakdown Voltage | V _(BR) CEO | 30 | | | V | Ic=100 μA |
| Emitter-Collector Breakdown Voltage | V _{(BR)ECO} | 5.0 | | | V | I _E =100 μA |
| Collector Dark Current | ICEO | | | 100 | nA | Vce=10 V, I _F =0 |
| COUPLED CHARACTERISTICS | | | | | | |
| On-State Collector Current | Ic(on) | | | | mA | |
| Parameter A | | 0.5 | | | | Vce=10, I _F =20 mA |
| (HOA0860/0865/0870/0875) | | | | | | |
| Parameter B | | 1.0 | | | | V _{CE} =5 V, I _F =10 mA |
| (HOA0861/0866/0871/0876) | | | | | | |
| Parameter C | | 1.8 | | | | Vce=0.6, I _F =20 mA |
| (HOA0862/0867/0872/0877) | | | | | | |
| Collector-Emitter Saturation Voltage | VCE(SAT) | | | | V | |
| Parameter A | | | | 0.4 | | Ic=0.4 mA, I _F =20 mA |
| (HOA0860/0865/0870/0875) | | | | | | , , |
| Parameter B | | | | 0.4 | | Ic=0.8 mA, I _F =10 mA |
| (HOA0860/0866/0871/0876) | | | | | | |
| Parameter C | | | | 0.6 | | Ic=1.8 mA, I _F =20 mA |
| (HOA0862/0867/0872/0877) | | | | 2.0 | | 3 112 1111 1, 11 29 11111 |
| Rise And Fall Time | t _r , t _f | | 15 | | μs | Vcc=5 V, Ic=1 mA |
| | | | _ | | , - | R _L =1000 Ω |

ABSOLUTE MAXIMUM RATINGS

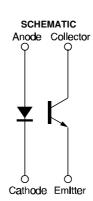
(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40°C to 85°C
Storage Temperature Range -40°C to 85°C
Soldering Temperature (5 sec) 240°C
IR EMITTER

Power Dissipation 100 mW (1)
Reverse Voltage 3 V
Continuous Forward Current 50 mA

DETECTOR
Collector-Emitter Voltage 30 V

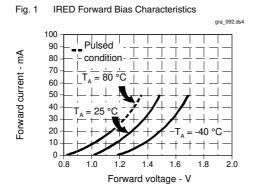
Emitter-Collector Voltage 5 V
Power Dissipation 100 mW (1)
Collector DC Current 30 mA



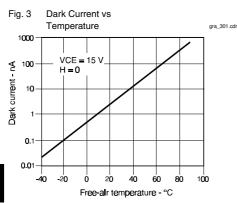
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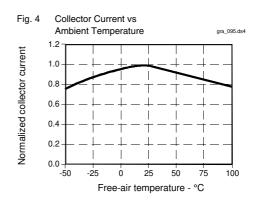
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Transmissive Sensor



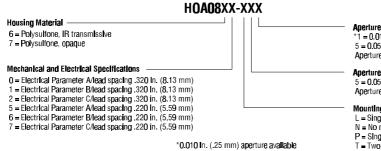
Non-Saturated Switching Time vs Load Resistance gra_093.ds4 SH Response time -+1+1+ ЦШЩ 三丰田田 TI TIT TITIIIIТПП 1000 100 10 Load resistance - Ohms





All Performance Curves Show Typical Values

PART NUMBER GUIDE



with electrical Parameter A only

Aperture Width In Front Of Detector

*1 = 0.010 ln. (0.25 mm) 5 = 0.050 ln. (1.27 mm) Aperture length is 0.060 in. (1.52 mm)

Aperture Width In Front Of IRED

5 = 0.050 In. (1.27 mm) Aperture length is 0.060 in. (1.52 mm)

Mounting Configuration

New Indianal Comparation

L = Single mounting tab, emitter side

N = No mounting tabs

P = Single mounting tab, detector side

T = Two mounting tabs

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